Unit: mm

TOSHIBA Insulated Gate Bipolar Transistor Silicon N Channel IGBT

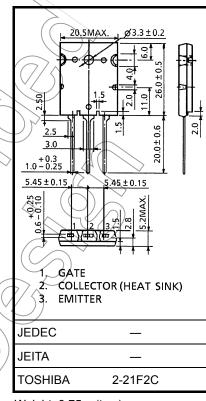
GT60J323H

Current Resonance Inverter Switching Application Induction Heating Cooking Appliances Induction Heating Appliances

- Enhancement mode type
- High speed: $t_f = 0.12 \mu s$ (typ.) (IC = 60A)
- Low saturation voltage: V_{CE} (sat) = 2.1 V (typ.) (IC = 60A)
- FRD included between emitter and collector
- Fourth generation IGBT
- TO-3P(LH) (Toshiba package name)

Absolute Maximum Ratings (Ta = 25°C)

| Characteristics | | Symbol | Rating | Unit | |
|------------------------------|--------------|----------------------|------------|--|--|
| Collector-emitter voltage | | V_{CES} | 600 | \\v | |
| Gate-emitter voltage | | V_{GES} | ±25 | \ | |
| Continuous collector current | @ Tc = 100°C | la. | 30 | > A | |
| | @ Tc = 25°C | IC | 60 | A | |
| Pulsed collector current | | I _{CP} | 120 | A | |
| Diode forward current | DC | l _F | 30 | A | |
| | Pulsed | IFP | 120 | <\A | |
| Collector power dissipation | @ Tc = 100°C | PC | 68 | w | |
| | @ Tc = 25°C | | 170 | | |
| Junction temperature | | ((T _j \) | 150 | \\°C | |
| Storage temperature range | | Tstg | -55 to 150 | \\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\ | |



Weight: 9.75 g (typ.)

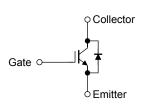
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions" Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

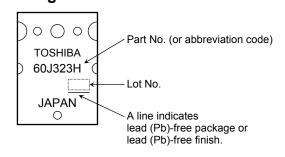
Thermal Characteristics

| Characteristics | ^ | Symbol | Max | Unit |
|----------------------------|-----|-----------------------|------|------|
| Thermal resistance (IGBT) | | R _{th} (j-c) | 0.74 | °C/W |
| Thermal resistance (diode) | >_< | R _{th} (j-c) | 1.56 | °C/W |

Equivalent Circuit



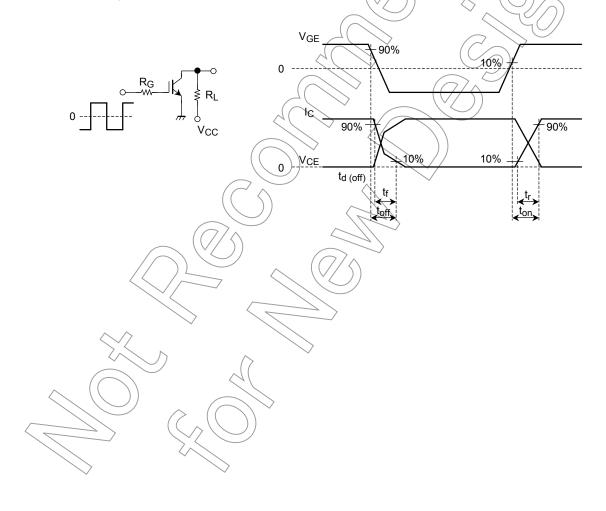
Marking



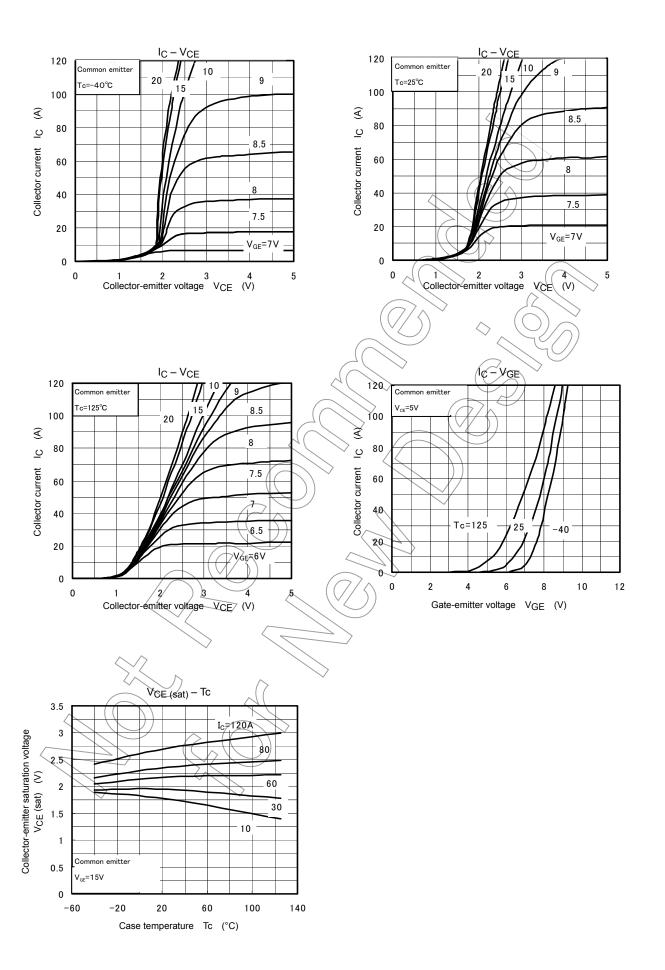
Electrical Characteristics (Ta = 25°C)

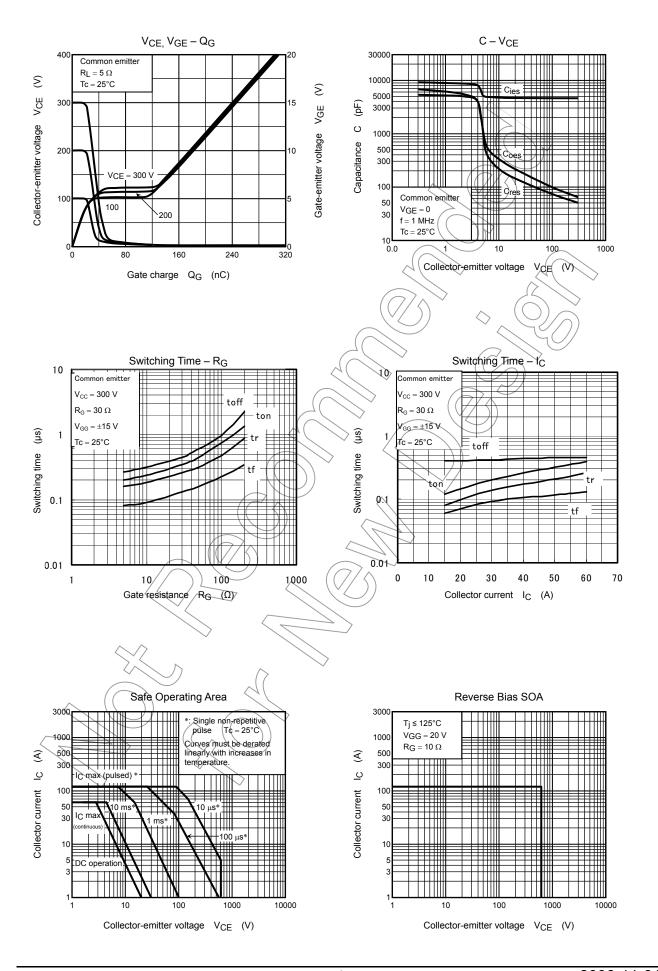
| Chara | acteristics | Symbol | Test Condition | Min | Тур. | Max | Unit |
|----------------------|--------------------|-----------------------|--|--------------|-------------|------|------|
| Gate leakage cur | rent | I _{GES} | V _{GE} = ±25 V, V _{CE} = 0 | _ | _ | ±500 | nA |
| Collector cut-off of | current | I _{CES} | V _{CE} = 600 V, V _{GE} = 0 | _ | _ | 1.0 | mA |
| Gate-emitter cut- | off voltage | V _{GE} (OFF) | I _C = 60 mA, V _{CE} = 5 V | 3.0 | _ | 6.0 | V |
| Collector-emitter | saturation voltage | V _{CE} (sat) | I _C = 60 A, V _{GE} = 15 V | | 2.1 | 2.9 | V |
| Input capacitance | 9 | C _{ies} | V _{CE} = 10 V, V _{GE} = 0, f = 1 MHz | (F | 4800 | _ | pF |
| Switching time | Rise time | t _r | Resistive Load | \ | 0.26 | _ | |
| | Turn-on time | t _{on} | V _{CC} = 300 V, I _C = 60 A | $\bigcirc)$ | 0.39 | _ | |
| | Fall time | t _f | $V_{GG} = \pm 15 \text{ V}, R_{G} = 30 \Omega$ | | 0.12 | 0.21 | μs |
| | Turn-off time | t _{off} | (Note 1) | <i>-</i> | 0.41 | _ | |
| Diode forward vo | Itage | V _F | I _F = 30 A, V _{GE} = 0 | _ | 1.4 | 2.0 | V |
| Reverse recovery | y time | t _{rr} | I _F = 30 A, di/dt = -100 A/µs | - / | 0.1 | 0.2 | μs |

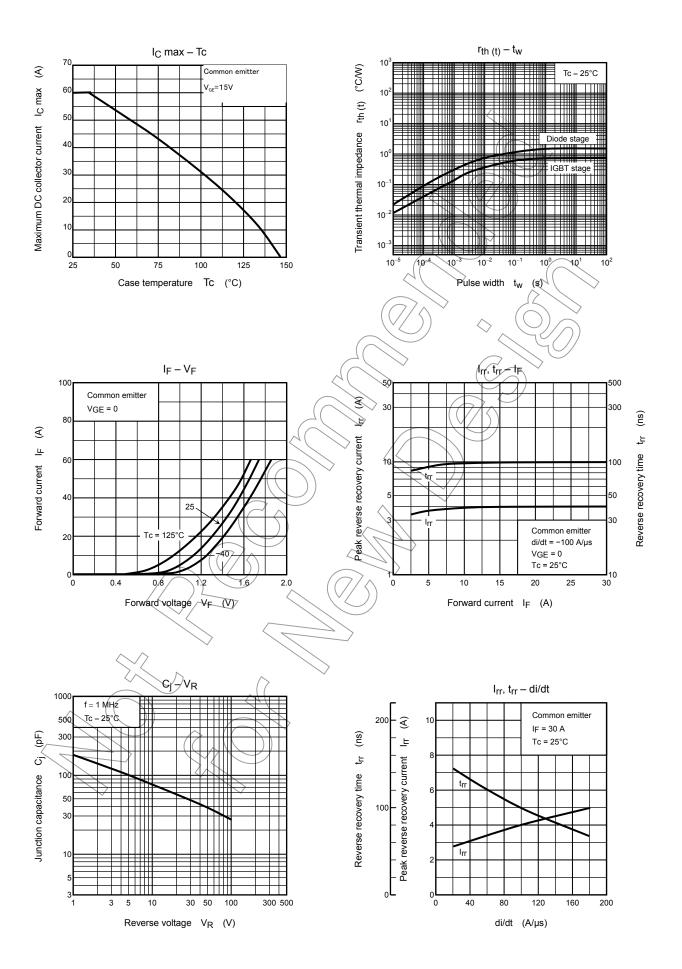


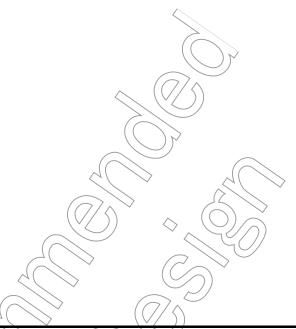


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